Mapping Image Potential States on Graphene Quantum Dots

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Free electron like image potential states are observed in scanning tunneling spectroscopy on graphene quantum dots on Ir(111) acting as potential wells. The spectrum strongly depends on the size of the nanostructure as well as on the spatial position on top, indicating lateral confinement. Further analysis of the substructure of the first state by spatial mapping of constant energy local density of states reveals characteristic patterns of confined states. The most pronounced state in the spectra is not the ground state, but an excited state with a favorable combination of the local density of states and parallel momentum transfer in the tunneling process. Chemical gating tunes the confining potential by changing the local workfunction. Our experimental determination of this workfunction allows to deduce the associated shift of the Dirac point.

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Confinement of electrons in nanostructures leads to quantum size effects as a size-dependent electronic structure and the appearance of atom-like states (characterized by a set of quantum numbers). In recent years, first experiments regarding the confinement of image potential states (IPSs) using the spatial resolution of the scanning tunneling microscope (STM) have been performed [1–6], transcending the pioneering studies based on two photon photoemission (2PPE) [7, 8]. IPSs are unoccupied states in an attractive image charge Coulomb potential between the Fermi and the vacuum level. Perpendicular to the surface they feature a hydrogen-like spectrum [9], whereas parallel to it a two dimensional electron gas (2DEG) forms. In STM, IPSs appear as peaks in the local density of states (LDOS) measured while retracting the tip from the surface. As they are Stark-shifted due to the electric field between tip and sample [10] they are often referred to as field emission resonances (FERs).

In order to observe and quantify confinement effects for IPSs, the corresponding nanostructures must fulfill four conditions: (i) a local workfunction \( \Phi \) smaller than that of the surrounding area [2], a large difference provides strong confinement, (ii) a well-defined shape, (iii) an established preparation that allows to adjust the size in a wide range, and (iv) stability under the high bias voltage used in the STM measurements. Whereas previous work provides fascinating first insights into quantum size effects for IPSs, no study yet matches all four conditions: In [3] a first hint at a size dependence of the energies of IPSs confined to Co islands on Au(111) is visible, however here the size variation was less than an order of magnitude. Atom-like patterns have been observed above stacking-fault tetrahedra on Ag(111) [5], still the difference in \( \Phi \) is so small that the resulting weak confinement only acts on the IPSs lowest in energy. The system NaCl on metal is promising as it shows a large difference in \( \Phi \). However, up to now there is no established method to tune the size of islands with a well-defined shape over a wide range [11, 12]. In consequence, in these experiments electron confinement has not been observed yet. Strong confinement is found for islands of alkali metals on Cu(100) [6]. In this case, the atomic structure of the islands is unclear, the size cannot be varied, and the clusters are not entirely stable during the measurement. A feature of special interest is the coupling between the IPSs on neighboring nanostructures to molecule-like states [3, 6, 13].

In this study, we demonstrate that confinement of IPSs can be observed in nanostructured epitaxial graphene (gr). IPSs on graphene are of special interest as they reveal specific properties of this material: As a consequence of its 2D-character a splitting of the first IPS has been predicted [14] and observed for gr/SiC [15]. Splitting of IPSs has also been observed for gr/Ru(0001) due to the strong corrugation of the carbon sheet which allows a large probability density also between graphene and the substrate [16, 17]. In the system under investigation here, 2PPE could demonstrate the parabolic bands of IPSs in the large band gap of the Ir substrate [18]. However, no effect of confinement could be determined due to the averaging nature of this method. On fundamental grounds, the IPSs on graphene share a common origin with specific electronic states of related materials [14] as the interlayer state of graphite, or superatomic states of fullerences [18].

For epitaxial graphene, the confining potential can be modified: The intercalation of electron acceptors (as, e.g. O [19]) between the carbon sheet and its substrate leads to a depletion of the charge density in graphene’s \( \pi \)-system, which in turn shifts the Dirac point \( E_D \) to higher electron energies [20], and vice versa for electron donors. Note that this chemical gating of graphene allows significantly larger shifts of \( E_D \) than electrostatic gating often applied in a field effect transistor geometry. Under the assumption that the band structure of graphene is rigidly pinned to the vacuum level [21], this shift is di-
rectly related to the change in the workfunction of the intercalated graphene $\Phi_{gr/s}$ with respect to the pristine case $\Phi_{gr}$: $\Phi_{gr/s} - \Phi_{gr} = E_D$. In consequence, the local doping level $E_D$ can be determined via a measurement of the local workfunction.

Nanostructured graphene is found in the system graphene quantum dots (GQD) on Ir(111) studied in this work, which fulfill all conditions outlined above: (i) a large workfunction difference $\Delta \Phi = \Phi_{gr} - \Phi_{st} = (4.65 \pm 0.10) \text{ eV} - (5.79 \pm 0.10) \text{ eV} = (-1.1 \pm 0.1) \text{ eV}$ [18], (ii) a well defined polygonal shape which can be determined with atomic precision [22], (iii) a size tunable from less than 10 nm² to electronically equivalent to infinite [23], and (iv) high stability also for high bias voltages due to the strong carbon-carbon bonds as well as the good conductivity of graphene. Fullerences [13] and carbon nanotubes [24] can be viewed as extreme cases of confinement. However, for such systems a tuning of the size over orders of magnitude is impossible and the curved geometry gives a new character to the now strongly hybridized states.

Our Ir(111) substrates are cleaned in ultra high vacuum by cycles of 1.5 keV Ar⁺ ion bombardment at room temperature, oxygen firing at 1120 K and annealing at 1470 K. Graphene is prepared by decomposition of ethylene in a temperature programmed growth process at 1270 K, resulting in a coverage of about 22% of a monolayer [23]. The STM tip is virtually grounded and the sample is put to the bias voltage $U$ leading to a tunneling current $I$. Energies are connected to $U$ by $E - E_F = e \cdot U$. IPSs are investigated by measuring the differential conductance in form of $dI/dU(E - E_F)$ point spectra and constant energy maps in constant current mode (stabilization values $U_{stab}$, $I_{stab}$) with active feedback loop by using the lock-in technique ($f = 1.317 \text{ kHz}$, $U_{mod} = 14 \text{ mV}$). Each point spectrum represents the average of at least two single measurements. Active feedback is of vital importance as moving the tip in z direction during point spectroscopy compensates for the Stark shift within one measurement [24]. The tip traces $z(V)$ were recorded parallel to the spectra. All data is taken at 5.3 K in a background pressure lower than $1 \times 10^{-11} \text{ mbar}$. Data analysis is performed using WSXM [25].

![Graphene Quantum Dots on Ir(111)](image)

**FIG. 1.** (color online). (a) Set of graphene quantum dots on Ir(111) [some of them labeled (A)-(G) with increasing size]; image size 55 nm x 90 nm, $U = 1 \text{ V}$, $I = 0.2 \text{ nA}$. (b) $dI/dU$ spectra on flakes (A) and (E); $U_{stab} = 1 \text{ V}$, $I_{stab} = 0.2 \text{ nA}$.
The spatial modulation of the LDOS can be resolved in two dimensions by $dI/dU$ mapping on a hexagonal flake, see Fig. 3. Here, we chose $n = 1$ in order to avoid the experimental difficulty of obtaining a high spatial resolution at high bias voltage (the particle-in-a-box behavior of IPSs does not depend on $n$). Again, the maximum of the TDOS-curve corresponds to (2,0), see Fig. 3(f). Indeed, the maps corresponding to the selected energies bear a strong resemblance to the eigenstates as depicted in Fig. 2(a): The state shown in Fig. 3(a) shows a broad maximum resembling (1,0), (b) is more peaked in the center like (2,0), and (c) and (d) have vanishing intensity in the center like (2,1). Strictly speaking, however, the patterns we observe are not pure states, but a superposition of several neighboring states. Note that in Fig. 3(d) and even more for (e) the breaking of the cylindrical symmetry by the hexagonal shape of the flake becomes evident. Similar patterns as the above have been observed on GQDs as a result of confinement of low energy states. Evaluating the above formula for the model island with $\Omega = 7.5 \text{ nm}^2$ indeed yields that (2,0) dominates for $0.36 \text{ nm} < z_0 < 1.04 \text{ nm}$. It is reasonable to assume that $z_0$ in our experiment is within these boundaries. The considerations on the tunneling probability and thus preferred states for tunneling may also connect to previous publications like [32], where the observed decrease in peak intensity could also be explained by less probable tunneling due to increased $k_z$ instead of an \textit{ad hoc} assumption of a peak broadening increasing with energy.

The electronic states of the LDOS can be calculated with $E_0^{(n)}(r,l)$ the energy of the state on extended graphene, $\Omega$ the area of the flake and $m^*$ the effective electron mass.

In Fig. 2(b) we show the dependence of $E^{(2)}$ and $E^{(3)}$ on $\Omega^{-1}$ for the whole set of flakes shown in Fig. 1(a). The bars correspond to the Gaussian full width half maximum (FWHM) of the respective peaks. A linear dependence can be fitted to the data (thin black lines), as expected for $E^{(n)}_{m,l}$, yielding $E_0^{(n)}$ as the intercept. With $m^* \approx m$, [15], we can calculate $E_{m,l}^{(n)}$. As we have measured the spectra always in the center of the flakes [see also Fig. 1(a)], we expect the dominant contribution from eigenstates with non vanishing amplitude at the center, i.e. $l = 0$, marked by the labeled lines in Fig. 2(b). Obviously the data fits best to the (2,0)-state, both for $n = 2$ and $n = 3$. This is surprising as this is not the ground state of the system. The dominance of (2,0) cannot be explained by the LDOS of the different eigenstates at the center of the flake, as this quantity increases monotonically with $m$ for $l = 0$ [see Fig. 2(a)]. For a correct interpretation, one has to take into account: Most of the tunneling electrons have a vanishing momentum parallel to the surface. However, for the electrons confined above the GQDs, $k_{m,l}$ increases with increasing order [see the values in Fig. 2(a)], making them less accessible for STS. In consequence, whereas the LDOS in the center increases with the order of the state, the contribution to the tunneling density of states (TDOS, e.g. [30]) measured in STM decreases. This fact can be quantified by TDOS $= \text{LDOS} \cdot \exp(-z_0/\lambda)$, with $\lambda^{-1} = 2\sqrt{2me\Phi/h^2 + k_{m,l}^2}$ and $k_{m,l} = z_{m,l}/r$. Therefore, the contribution of a given state $(m,l)$ to the signal observed in STM depends on the tip-sample distance $z_0$, the radius of the flake $r$, and the order of the state. Evaluating the above formula for the model island with $\Omega = 7.5 \text{ nm}^2$ indeed yields that (2,0) dominates for $0.36 \text{ nm} < z_0 < 1.04 \text{ nm}$. It is reasonable to assume that $z_0$ in our experiment is within these boundaries. The considerations on the tunneling probability and thus preferred states for tunneling may also connect to previous publications like [32], where the observed decrease in peak intensity could also be explained by less probable tunneling due to increased $k_z$ instead of an \textit{ad hoc} assumption of a peak broadening increasing with energy.

The whole series of IPSs is down-shifted on a GQD with $\Phi$ across the boundary region is indeed yields that (2,0) dominates for $0.36 \text{ nm} < z_0 < 1.04 \text{ nm}$. It is reasonable to assume that $z_0$ in our experiment is within these boundaries. The considerations on the tunneling probability and thus preferred states for tunneling may also connect to previous publications like [32], where the observed decrease in peak intensity could also be explained by less probable tunneling due to increased $k_z$ instead of an \textit{ad hoc} assumption of a peak broadening increasing with energy.

The spatial modulation of the LDOS can be resolved in two dimensions by $dI/dU$ mapping on a hexagonal flake, see Fig. 3. Here, we chose $n = 1$ in order to avoid the experimental difficulty of obtaining a high spatial resolution at high bias voltage (the particle-in-a-box behavior of IPSs does not depend on $n$ [33]). Again, the maximum of the TDOS-curve corresponds to (2,0), see Fig. 3(f). Indeed, the maps corresponding to the selected energies bear a strong resemblance to the eigenstates as depicted in Fig. 2(a): The state shown in Fig. 3(a) shows a broad maximum resembling (1,0), (b) is more peaked in the center like (2,0), and (c) and (d) have vanishing intensity in the center like (2,1). Strictly speaking, however, the patterns we observe are not pure states, but a superposition of several neighboring states. Note that in Fig. 3(d) and even more for (e) the breaking of the cylindrical symmetry by the hexagonal shape of the flake becomes evident. Similar patterns as the above have been observed on GQDs as a result of confinement of low energy occupied states [24]. Finally, the inversion of contrast in Fig. 3(e) indicates that the LDOS at this energy is dominated by Ir IPSs, drawing our attention to the interaction of the IPS-2DEGs above graphene and Ir(111). The whole series of IPSs is down-shifted on a GQD with respect to Ir(111) due to the lowered $\Phi$. Mapping the IPSs along lines cutting through a GQD (see [24]) shows that this shift for $n = 1$ across the boundary region is rather abrupt, whereas all higher orders show a more continuous way of change. This indicates a suppressed interaction for $n = 1$ and interacting IPS-2DEGs of the flake and the substrate for $n > 1$.
FIG. 3. (color online). (a)-(e) IPS $n = 1$ by 2D constant energy mapping of $dI/dU$ on a $\Omega = 11$ nm² sized gr island. (a)-(e): $E - E_F = 4.50$ eV, 4.73 eV, 4.82 eV, 4.98 eV, 5.22 eV; $I = 0.2$ nA; image size: all $5.7 \times 5.7$ nm². (f) $dI/dU(E - E_F)$ spectrum of $n = 1$ with energies of maps shown in (a)-(e) (black squares), $E_{\text{m},l}^{(1)}$ indicated by solid (dashed) lines for $l = 0$ ($l \neq 0$); $E_0^{(1)}$ as $E_0^{(2,3)}$ in Fig. 2(b).

In the following, we will exemplify chemical gating of graphene for the case of O. The preparation described above is extended by exposing the sample to 750 L of O₂ at 430 K. This process leads to O intercalation for all but the smallest flakes [19]. In order to demonstrate the effect of intercalation most clearly, we will focus on the largest flakes which are representative for extended graphene. Fig. 2(a) shows an STM image of O-intercalated graphene. The superstructure already visible in this image can be accurately determined as $(\sqrt{3} \times \sqrt{3})R30°$ using the Fourier transform shown in Fig. 2(c), i.e. a coverage of 0.33 ML. In Fig. 2(b) we compare spectra on gr/O/Ir (blue line) and on O/Ir(111) (black line). The difference $\Phi$ can be determined from a plot $\Delta E^{(n)} = E_{\text{gr/O/Ir}}^{(n)} - E_{\text{O/Ir}}^{(n)}$ versus $n$ [33], see inset of Fig 2(b), as $\Delta \Phi = (-1.3 \pm 0.1)$ eV, leading to $\Phi_{\text{gr/O/Ir}} = (5.1 \pm 0.1)$ eV, which has to be compared with $\Phi_{\text{gr/Ir}} = (4.7 \pm 0.1)$ eV [18, 34].

According to [21], one can deduce $\Delta E_D = E_{\text{D,gr/O/Ir}} - E_{\text{D,gr/Ir}} = \Phi_{\text{gr/O/Ir}} - \Phi_{\text{gr/Ir}} = (0.4 \pm 0.1)$ eV from our experiments. This nicely agrees with $\Delta E_D = 0.3$ eV implied by a recent photoemission study [20] (linearly interpolated using the experimentally determined value of $\Delta E_D = 0.6$ eV for 0.6 ML intercalated O). In consequence, our determination of the local workfunction provides direct access to the position of the Dirac point $E_D$, which is often hard to determine by other methods. As an example, for gr/Ir(111) the LDOS determined using STS does not show a pronounced dip at $E_D$ [35]. A determination of $E_D$ via $\Phi$ can be especially useful for mapping the doping level in inhomogeneous graphene systems.

As an outlook, the suitability of graphene as building material for the nanostructures as demonstrated here opens new possibilities for the investigation of laterally confined IPSs, as there are various methods on how to prepare rationally designed architectures based on graphene: It can be cut by STM lithography [36], allowing complicated well geometries. A clever choice of the hydrocarbon precursor leads to the formation of superperiodic structures [37] which may give rise to backfolding of the IPS bands. One can envision that it is possible to move GQDs with an STM tip moving in close proximity to the surface, allowing exact studies of the interaction of neighboring quantum wells. Such structures would resemble a diatomic molecule, where the participating quantum wells can even have different energy levels due to a variation in size or in doping.

Summing up our results, the large difference in workfunction between graphene and Ir(111), the well defined shape of the nanostructures as well as their large size variation and high stability enabled us to demonstrate confinement effects of IPSs. We have shown that the energy spectrum depends on the size of the GQDs and evolves into a series of atom-like states, which is dominated by a state other than the ground state due to an interplay of density of states and parallel momentum transfer in the tunneling process. Intercalating extended graphene with an electron acceptor introduces an additional degree of freedom as this allows tuning of $\Phi$. The determination of the local workfunction allows to deduce...
the local doping level $E_D$. Our findings open new possibilities for the study of quantum size effects as graphene is a very flexible building material for nanostructures.

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